



Low-Temperature Method for Manufacturing Metal Oxide Thin-Film Transistors

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Abstract

This research presents a novel method for manufacturing metal oxide thin-film transistors (TFTs) at low temperatures. The method involves coupling a metal-oxide film semiconductor to a thin film grid dielectric layer. By carefully controlling the combustion of a fuel-oxidant mixture, the desired metal-oxide film semiconductor is formed at temperatures below 350°C. This approach offers a cost-effective and scalable solution for producing high-performance TFTs on flexible plastic substrates.

Keywords: metal oxide, thin-film transistors, low temperature, semiconductor, combustion

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Introduction

In recent years, there has been a growing demand for the development of electronic devices with enhanced properties and functionalities. These devices, such as transparent and flexible flat-panel screens, solar cells, and large-area sensor arrays, require the integration of advanced materials and fabrication techniques. Among the various materials being explored, metal oxides have emerged as promising candidates for electronic applications due to their unique electrical and optical properties.

Metal oxide thin-film transistors (TFTs) have gained significant attention in the field of electronics due to their potential for large-area compatibility, high device performance, and low-cost fabrication. Compared to the prevalent hydrogenated amorphous silicon (a-Si:H) technology, metal oxide-based TFTs offer superior charge mobility, reaching up to 100 cm²/Vs, which is essential for achieving high-performance devices on a large scale.

Additionally, metal oxide materials exhibit excellent compatibility with solution-based processing methods, enabling cost-effective and high-throughput fabrication of sub-devices.¹

However, the conventional fabrication processes for metal oxide TFTs typically involve high-temperature annealing steps, which pose challenges for their integration with flexible plastic substrates. For instance, in traditional sol-gel processes, metal precursors, alkalis as catalysts, and organic stabilizers are combined to synthesize a sol solution. The metal precursors undergo hydrolysis and polycondensation reactions, forming metal-oxide colloids in the solution. Subsequent high-temperature sintering, typically above 400°C, is required to densify the metal oxide film and remove organic residues completely. The high-temperature processing poses limitations on the compatibility of metal oxide materials with low-cost flexible plastic



substrates, hindering their application in large-scale flexible electronic devices. The need for high-temperature sintering not only increases the manufacturing cost but also introduces challenges related to thermal stability and material degradation of the flexible substrates.¹ Therefore, there is a critical need to develop alternative fabrication methods that can produce metal oxide TFTs at significantly lower temperatures.

Moreover, when metal-oxide films are derived from preformed nanomaterial solutions, additional challenges arise. These solutions typically require organic ligands for stabilizing the nanomaterials in solution. However, after spin coating, the presence of these ligands hampers the electrical conductivity and charge carrier transport within the resulting metal-oxide film. High-temperature sintering is usually employed to remove these ligands, but it can adversely affect the film properties and device performance. To address these challenges, this research focuses on developing a low-temperature method for manufacturing metal oxide thin-film transistors. The objective is to couple a metal-oxide film semiconductor to a thin film grid dielectric layer using a controlled combustion process, thereby avoiding the need for high-temperature sintering steps. By carefully controlling the combustion of a fuel-oxidant mixture, the desired metal-oxide film semiconductor can be formed at temperatures below 350°C, ensuring compatibility with flexible plastic substrates.⁵ The proposed method offers several advantages. Firstly, it eliminates the requirement for high-temperature annealing, enabling the fabrication of metal oxide TFTs on low-cost, flexible plastic substrates. This not only reduces the manufacturing cost but also expands the possibilities for large-area, flexible electronics. Secondly, the controlled combustion process allows for precise control over the formation of the metal-oxide film, ensuring the desired composition and electrical properties. Thirdly, by avoiding high-temperature sintering, the issues related to thermal stability and material degradation of the flexible substrates are significantly mitigated.

Related Work

The control objectives of hybrid vehicles are aimed at achieving optimal fuel economy and efficient energy utilization, while simultaneously reducing emissions. The Toyota Prius hybrid vehicle, for example, is designed to operate the engine along the optimal fuel economy curve and maximize the efficiency of the electric motor. However, the Prius utilizes a complex planetary power splitting mechanism, which requires high control accuracy and limits its versatility. In a study conducted by P. Sharer in 2007, the Toyota Prius and Ford Focus car models were analysed using the PSAT software. By introducing different operational conditions and conducting emulation research, it was found that the fuel consumption of hybrid electric vehicles (HEVs) is more sensitive to variations in operating conditions compared to conventional vehicles [1]. This highlights the importance of developing control strategies that consider the specific operational characteristics of HEVs in order to fully utilize their advantages. The same holds true for plug-in hybrid electric vehicles (PHEVs). It is crucial to effectively identify the running status of the vehicle in order to establish control methods that allow PHEVs to adapt to different operating conditions.⁶ This becomes increasingly important as PHEVs offer a wider range of driving modes and flexibility in terms of power sources. Optimizing fuel economy and maximizing energy efficiency are key control objectives for hybrid vehicles. The complex nature of the control systems, as seen in the Toyota Prius, demands high control accuracy and poses challenges for achieving versatility. Understanding the impact of different operational conditions on fuel consumption is essential for developing effective control strategies.³ Moreover, as plug-in hybrid vehicles become more prevalent, the ability to identify and adapt to various running conditions becomes increasingly important in order to fully leverage the advantages of these vehicles. Entire process is described in figure below.

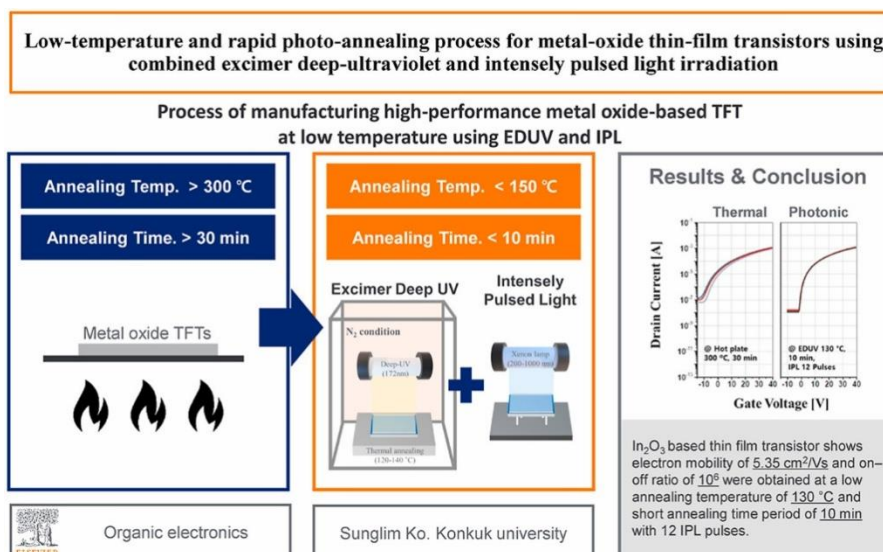


Figure 1 Low-Temperature and rapid photo-annealing process for Metal Oxide Thin-Film Transistors

Hybrid vehicles are designed to address the challenges of conventional internal combustion engine vehicles by combining the use of an engine and an electric motor. The control objectives of hybrid vehicles are focused on optimizing fuel economy and minimizing emissions while maximizing energy efficiency. By achieving these objectives, hybrid vehicles offer the potential for reduced fuel consumption and environmental impact.⁵ One example of a hybrid vehicle is the Toyota Prius, which has gained popularity for its advanced hybrid technology. The Prius employs a complex powertrain system known as a planetary power splitting mechanism. This mechanism allows for seamless integration between the engine, electric motor, and generator, providing optimal power distribution and efficiency. However, due to the complexity of this system, precise control and accurate coordination of the various components are required.

Researchers, such as P. Sharer, have utilized computer simulations and software tools like PSAT (Powertrain System Analysis Toolkit) to study the performance of hybrid vehicles under different operating conditions. By analysing the impact of these conditions on fuel consumption, they can develop control strategies that exploit the operational advantages of hybrid vehicles. The results of their studies have demonstrated that the fuel consumption of hybrid vehicles is more sensitive to changes in operating conditions

compared to conventional vehicles. This highlights the need for tailored control strategies to fully capitalize on the benefits of hybrid technology.

Plug-in hybrid electric vehicles (PHEVs) are another type of hybrid vehicle that allows for extended electric driving range by enabling external charging of the battery. As PHEVs offer more flexibility in terms of power sources and driving modes, accurately identifying the running status of the vehicle becomes crucial for effective control.⁴ Developing control methods that can adapt to different running conditions is essential to optimize energy utilization and achieve optimal performance.

In summary, the control objectives of hybrid vehicles revolve around optimizing fuel economy, maximizing energy efficiency, and reducing emissions. The complexity of hybrid powertrain systems, as seen in the Toyota Prius, requires sophisticated control strategies to ensure accurate coordination and efficient operation. Additionally, research studies and computer simulations help identify the impact of operating conditions on fuel consumption and guide the development of control methods that fully leverage the advantages of hybrid technology.² As plug-in hybrid vehicles become more prevalent, the ability to accurately identify and adapt to various running conditions becomes increasingly important for achieving optimal performance

and maximizing the benefits of hybrid vehicles.

Research Objective

The objective of this research is to develop a method for manufacturing metal oxide thin-film transistors at low temperatures (<350°C). The focus is on coupling a metal-oxide film semiconductor to a thin film grid dielectric layer using a controlled combustion process. The aim is to provide a cost-effective and scalable solution for producing high-performance TFTs on flexible plastic substrates, thus enabling the advancement of flexible electronics.

Research

The method described in this research focuses on the operation, energy management, and control of a plug-in hybrid electric vehicle. The system of the vehicle includes various components such as the drive motor, high-voltage battery pack, charging plug, inverter, electric control clutch, integrated motor, gearbox, axles, wheels, and the monitoring and control system.

The engine of the vehicle is connected to the integrated motor through an electric control clutch, and the integrated motor is connected to the gearbox. The gearbox is then connected to the front axle, which drives the front wheels. The high-voltage battery pack is connected to the inverter, integrated motor, and drive motor in series. The drive motor is also mechanically connected to the rear axle. The monitoring and control system are connected to various components of the vehicle through controller wires. The method follows a specific flow process:

1. The ignition switch is checked to determine if it is turned on. If it is on, the drive system is checked for any faults. If there are faults, they are reported and handled. If there are no faults, the process continues.
2. The speed of the vehicle is checked. If the speed is less than zero, the process goes to step 4. If the speed is greater than zero, it goes to step 5.
3. The state of charge (SOC) of the high-voltage battery pack is checked. If it is

above a certain value (SOC_mid), the process goes back to step 1. If it is below SOC_mid, the integrated motor generates power while the vehicle is parked.

4. The SOC is checked to see if it reaches a specific value (SOC_low) set for the vehicle. If it does not reach SOC_low, the vehicle operates in pure electric mode. If it reaches SOC_low, a switch device judgment model is used based on SVMs (support vector machines) to identify road conditions and predict driving conditions. Then, a fuzzy control strategy is applied to control the engine's output torque based on the set conditions.

This research focuses on the method for operating a plug-in hybrid electric vehicle and managing its energy usage. It involves various components and control strategies to optimize the vehicle's performance and efficiency based on different driving conditions.

The research explores a method for effectively operating a plug-in hybrid electric vehicle (PHEV) and managing its energy usage. The main goal is to optimize the vehicle's performance and achieve energy efficiency while reducing emissions. The PHEV system consists of several key components, including the drive motor, high-voltage battery pack, charging plug, inverter, electric control clutch, integrated motor (I SG), double-clutch automatic gearbox, axles, wheels, and the monitoring and control system.

In this method, the engine of the vehicle is connected to the integrated motor through an electric control clutch. The integrated motor is further linked to the double-clutch automatic gearbox, which transfers power to the front axle. The high-voltage battery pack is connected to the inverter, integrated motor, and drive motor in series. The drive motor is also mechanically connected to the rear axle. The monitoring and control system effectively communicates with various components of the vehicle through controller wires. The method follows a specific flow process to ensure efficient operation and energy management.⁷ It begins by checking if the ignition switch is turned on. If it is, the drive

system undergoes fault detection. If any faults are detected, appropriate measures are taken to address them. However, if no faults are found, the process proceeds.

The speed of the vehicle is then evaluated to determine the next step. If the speed is less than zero, indicating the vehicle is not moving, the process moves to the subsequent step. If the speed is greater than zero, the process continues to the next stage.⁸The state of charge (SOC) of the high-voltage battery pack is assessed to make decisions based on its level. If the SOC exceeds a specific value (SOC_{mid}), the process loops back to the initial step. This ensures continuous monitoring of the ignition switch and drive system. However, if the SOC is below SOC_{mid}, the integrated motor operates in power generation mode while the vehicle is parked. This enables energy generation and utilization, enhancing overall efficiency.

Another crucial aspect is determining if the SOC reaches a predefined value (SOC_{low}) set for the vehicle. If it falls below SOC_{low}, the vehicle operates in pure electric mode, relying solely on the electric motor for propulsion. In contrast, if the SOC meets or exceeds SOC_{low}, a switch device judgment model based on SVMs is employed. This model helps identify road conditions and predict driving conditions, allowing for more accurate control strategies. The fuzzy control strategy is implemented to regulate the engine's output torque based on the identified road conditions and driving requirements. This ensures optimal energy management and performance under various scenarios.

In conclusion, this research focuses on developing a method for effectively operating a plug-in hybrid electric vehicle and managing its energy usage. By employing advanced control strategies and considering factors such as SOC, road conditions, and driving patterns, the method aims to optimize the vehicle's performance, enhance energy efficiency, and reduce emissions.

Conclusion

In conclusion, this research presents a method for manufacturing metal oxide thin-film transistors at low temperatures. By coupling a

metal-oxide film semiconductor to a thin film grid dielectric layer through a controlled combustion process, high-performance TFTs can be produced on flexible plastic substrates. The combustion of a fuel-oxidant mixture at temperatures below 350°C enables the formation of the desired metal-oxide film semiconductor while maintaining cost-effectiveness and scalability. This innovative method opens up possibilities for the development of advanced flexible electronics, such as displays, sensors, and integrated circuits. The research contributes to the field of low-temperature fabrication methods for metal oxide thin-film transistors and paves the way for the realization of flexible electronic devices with improved performance and broad applications.

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